

2SJ517 Silicon P Channel MOS FET

REJ03G0874-0400 (Previous: ADE-208-575B) Rev.4.00 Sep 07, 2005

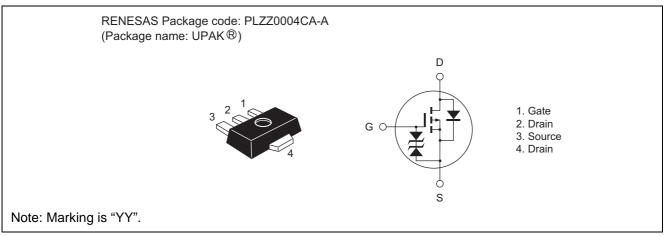
Description

High speed power switching

Features

- Low on-resistance $R_{DS\;(on)}=0.18\;\Omega\;typ.\;(at\;V_{GS}=-4\;V,\,I_D=-1\;A)$
- Low drive current
- High speed switching
- 2.5 V gate drive devices.

Outline



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Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	-20	V
Gate to source voltage	V _{GSS}	±10	V
Drain current	ID	-2	A
Drain peak current	I _{D (pulse)} Note 1	-4	A
Body to drain diode reverse drain current	I _{DR}	-2	A
Channel dissipation	Pch Note 2	1	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	۵°

Notes: 1. PW \leq 100 $\mu s,$ duty cycle \leq 10%

2. When using the aluminium ceramic board (12.5 \times 20 \times 0.7 mm)

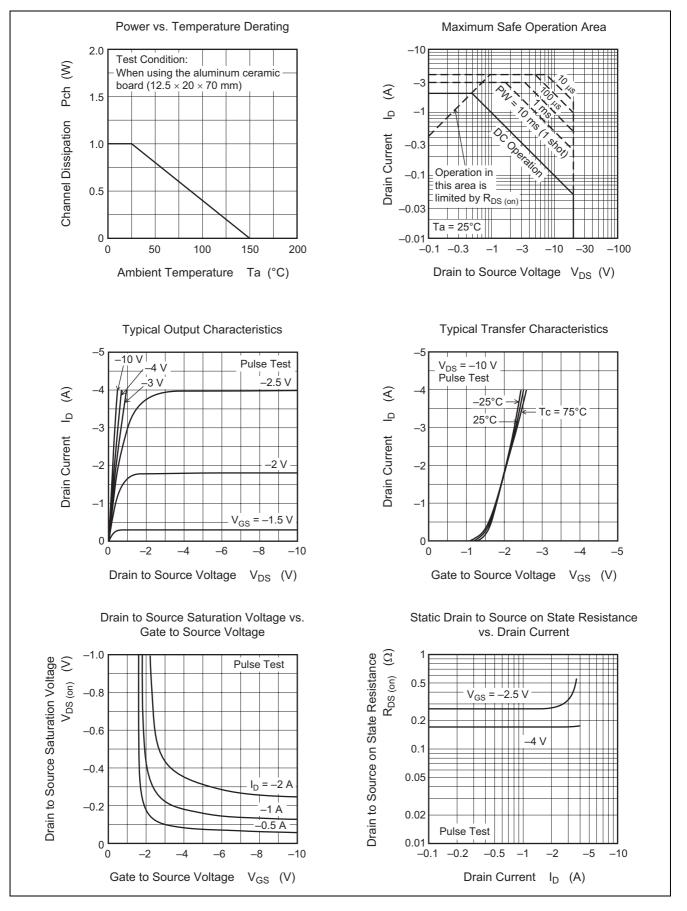
Electrical Characteristics

						(Ta = 25°C)
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V (BR) DSS	-20	—	_	V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V (BR) GSS	±10	—	—	V	$I_{G} = \pm 100 \ \mu A, \ V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	—	—	-10	μA	$V_{DS} = -20 V, V_{GS} = 0$
Gate to source leak current	I _{GSS}	—	—	±10	μA	$V_{GS} = \pm 8 \text{ V}, V_{DS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	-0.5	—	-1.5	V	$I_D = -1 \text{ mA}, V_{DS} = -10 \text{ V}$
Static drain to source on state resistance	R _{DS (on)}	—	0.18	0.24	Ω	$I_D = -1 A, V_{GS} = -4 V^{Note 3}$
	R _{DS (on)}	—	0.27	0.43	Ω	$I_D = -1 \text{ A}, V_{GS} = -2.5 \text{ V}^{\text{Note 3}}$
Forward transfer admittance	y _{fs}	1.8	3.0	_	S	$I_D = -1 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 3}}$
Input capacitance	Ciss	_	320	_	pF	$V_{DS} = -10 V$
Output capacitance	Coss	_	190	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	90	_	pF	f = 1 MHz
Turn-on delay time	t _{d (on)}	_	14	_	ns	$V_{GS} = -4 V$
Rise time	tr	_	75	_	ns	$I_D = -1 A$
Turn-off delay time	t _{d (off)}	_	90	_	ns	R _L = 10 Ω
Fall time	t _f	_	90	_	ns	
Body to drain diode forward voltage	V _{DF}		-0.95		V	$I_F = -2 A, V_{GS} = 0$
Body to drain diode reverse recovery	t _{rr}		70		ns	$I_F = -2 A, V_{GS} = 0$
time						di _F /dt = 50 A/µs

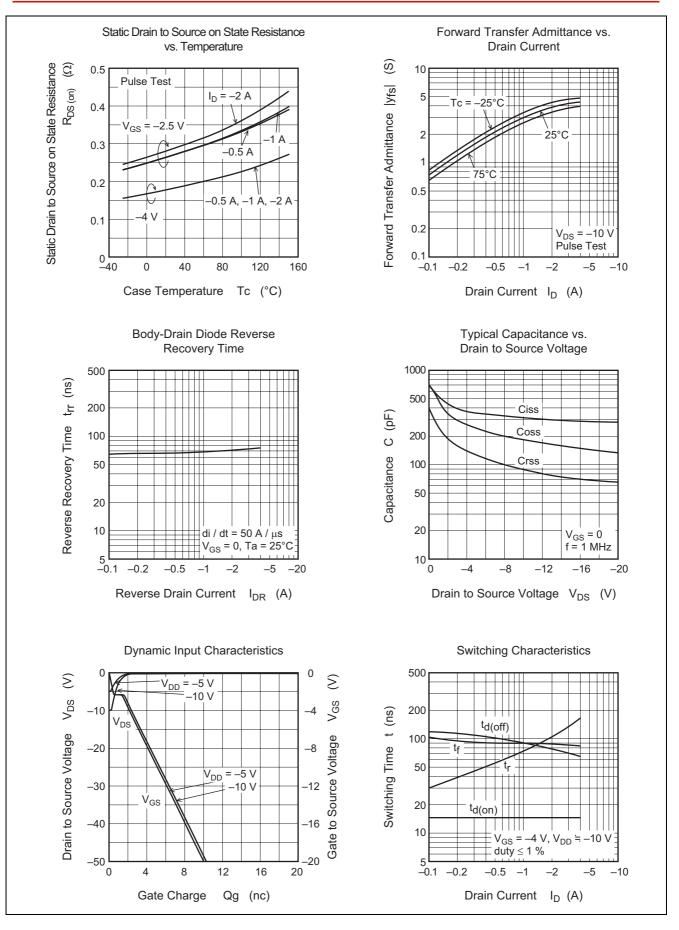
Note: 3. Pulse test



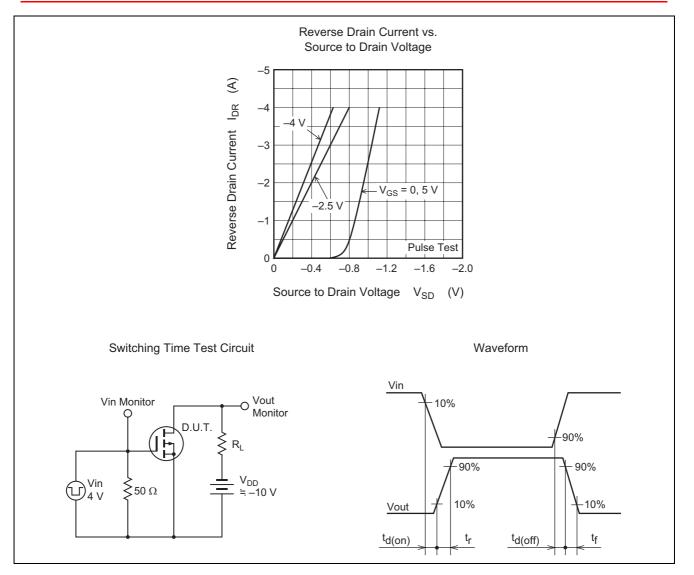
Main Characteristics





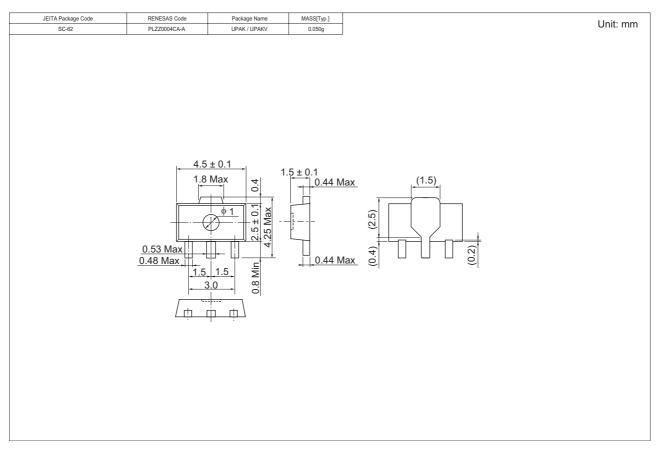








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
2SJ517YYTL-E	1000 pcs	Taping
2SJ517YYTR-E	1000 pcs	Taping

Note: For some grades, production may be terminated. Please contact the Renesas sales office to check the state of production before ordering the product.



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